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Attorney Docket No. 00P9102US

**DECLARATION FOR PATENT APPLICATION, POWER OF
ATTORNEY & DESIGNATION OF CORRESPONDENCE ADDRESS**

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PETITIONS OFFICE

As below named inventor, I hereby declare that:

My residence, post office address and citizenship are as stated below next to my name.

I believe I am the original, first and sole inventor (if only one name is listed below) or an original, first and joint inventor (if plural names are listed below) of the subject matter that is claimed and for which a patent is sought on the invention entitled:

**Method for Fabricating Transistors having Damascene Formed Gate Contacts and Self-
Aligned Borderless Bit Line Contacts**

the specification of which (check one)

☐ Is attached hereto.

☒ was filed on December 19, 2000 as Application Serial No. 09/740,113
and was amended on _____ (if applicable).

I hereby state that I have reviewed and understand the contents of the above-identified specification including the claims, as amended by any amendment referred to above.

I acknowledge the duty to disclose information that is material to the examination of this application in accordance with 37 CFR §1.56(a).

**PRIOR FOREIGN/PCT APPLICATION(S) FILED WITHIN 12 MONTHS (6 MONTHS FOR
DESIGN) PRIOR TO THIS APPLICATION AND ANY PRIORITY CLAIMS UNDER 35 U.S.C. §
119(a)-(d)**

I hereby claim foreign priority benefits under 35 USC §119 of any foreign application(s) for patent or inventor's certificate listed below and have also identified below any foreign application for patent or inventor's certificate having a filing date before that of the application on which priority is claimed:

Prior Foreign Application(s)			Priority Claimed	
Number	Country	Day/Month/Year Filed	Yes	No

Infocoon Docket No. 00P9102US

CLAIM FOR BENEFIT OF PRIOR U.S. PROVISIONAL APPLICATION(S)
(35 U.S.C. § 119(e))

I hereby claim the benefit under Title 35, United States Code, § 119(e) of any United States provisional application(s) listed below:

Provisional Application Number	Filing Date

CLAIM FOR BENEFIT OF EARLIER US/PCT APPLICATION(S)
UNDER 35 U.S.C. 120

I hereby claim the benefits under 35 USC §120 of any United States application(s) listed below and, insofar as the subject matter of each of the claims of this application is not disclosed in the prior United States application in the manner provided by the first paragraph of 35 USC §112, I acknowledge the duty to disclose material information as defined in 37 CFR §1.56 which occurred between the filing date of the prior application and the national or PCT international filing date of this application:

Appl. No.	Filing Date	Patented, Pending, Abandoned

Power of Attorney: As a named inventor, I hereby appoint the following attorney(s) and/or agent(s) to prosecute this application and transact all business in the Patent and Trademark Office connected therewith.

Erik O. Berger, Reg. No. 42,315; Stanton C. Braden, Reg. No. 32,556; Marie-Claire B. Maple, Reg. No. 37,588; and all practitioners at Customer No. 25962.

Send Correspondence to:

Ira S. Matsil
Slater & Matsil, L.L.P.
17950 Preston Road, Suite 1000
Dallas, Texas 75252

Direct telephone calls to:
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Infineon Docket No. 00P9102US

I hereby declare that all statements made herein on my own knowledge are true and that all statements made on information and belief are believed to be true, and further that these statements were made with the knowledge that willful false statements and the like so made are punishable by fine or imprisonment, or both under 18 USC §1001 and that such willful false statements may jeopardize the validity of the application or any patent issuing thereon.

Full Name of First Inventor: Mibel Seitz	
Inventor's Signature: <i>M. Seitz</i>	Date: <i>Sep 5, 2003</i>
Residence: Radebeul, Germany	
Citizenship: Austria	
Post Office Address: Patty Frank Weg 18, Radebeul, Germany 01445	

Full Name of Second Inventor: Michael Wise	
Inventor's Signature:	Date:
Residence: Lagrangeville, NY, US	
Citizenship: US	
Post Office Address: 260 Walsh Rd., Lagrangeville, NY, US 12540	

Full Name of Third Inventor: Christian Dubuc	
Inventor's Signature:	Date:
Residence: San Diego, CA, US	
Citizenship: Canada	
Post Office Address: 3889 Fallon Circle, San Diego, CA, US 92130	

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Full Name of First Inventor: Mihel Seitz	
Inventor's Signature:	Date:
Residence: Radebeul, Germany	
Citizenship: Austria	
Post Office Address: Patty Frank Weg 18, Radebeul, Germany 01445	

Full Name of Second Inventor: Michael Wise	
Inventor's Signature: <i>Michael Wise</i>	Date: 9/2/03
Residence: Lagrangeville, NY, US	
Citizenship: US	
Post Office Address: 260 Walsh Rd., Lagrangeville, NY, US 12540	

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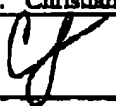
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Inventor's Signature: 	Date: 07/02/03
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Citizenship: Canada	
Post Office Address: 12720 Richer, Saint-Hyacinthe, Quebec, J2T 2P5, Canada	